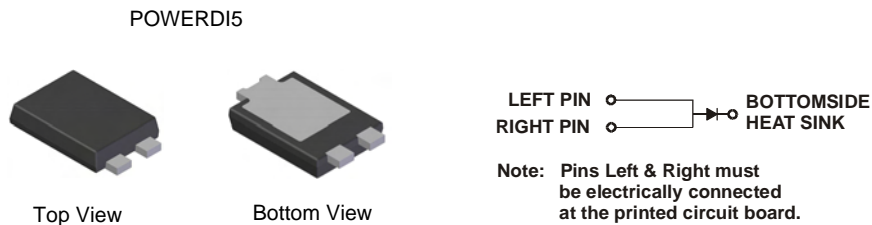


Features

- Guard Ring Die Construction for Transient Protection
- Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- High Forward Surge Current Capability
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: POWERDI5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 0.094 grams (approximate)

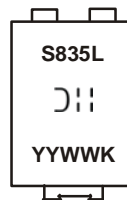


Ordering Information (Note 4)

Part Number	Case	Packaging
PDS835L-13	POWERDI5	5000/Tape & Reel
PDS835L-7	POWERDI5	1500/Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com>.

Marking Information



- S835L = Product type marking code
- ⏏ = Manufacturers' code marking
- YYWW = Date code marking
- YY = Last two digits of year (ex: 04 for 2004)
- WW = Week code (01 - 53)
- K = Factory Designator

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.
For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	35	V
Working Peak Reverse Voltage	V _{RWM}		
DC Blocking Voltage	V _R		
RMS Reverse Voltage	V _{R(RMS)}	25	V
Average Rectified Output Current (See also figure 5)	I _O	8	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	120	A

Thermal Characteristics

Characteristic	Symbol	Typ	Max	Unit
Thermal Resistance Junction to Soldering Point	R _{θJS}	—	3.0	°C/W
Thermal Resistance Junction to Ambient Air (Note 5) T _A = +25°C	R _{θJA}	100	—	°C/W
Thermal Resistance Junction to Ambient Air (Note 6) T _A = +25°C	R _{θJA}	65	—	°C/W
Thermal Resistance Junction to Ambient Air (Note 7) T _A = +25°C	R _{θJA}	45	—	°C/W
Operating Temperature Range	T _J	-65 to +125		°C
Storage Temperature Range	T _{STG}	-65 to +150		°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 8)	V _{(BR)R}	35	—	—	V	I _R = 1mA
Forward Voltage	V _F	—	0.46	0.51	V	I _F = 8A, T _S = +25°C I _F = 8A, T _S = +125°C
Reverse Leakage Current (Note 8)	I _R	—	0.05	1.4	mA	T _S = +25°C, V _R = 35V T _S = +100°C, V _R = 35V

- Notes:
- FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per <http://www.diodes.com>
 - Polymide PCB, 2 oz. Copper, minimum recommended pad layout per <http://www.diodes.com>.
 - Polymide PCB, 2 oz. Copper. Cathode pad dimensions 9.4mm x 7.2mm. Anode pad dimensions 2.7mm x 1.6mm.
 - Short duration pulse test used to minimize self-heating effect.

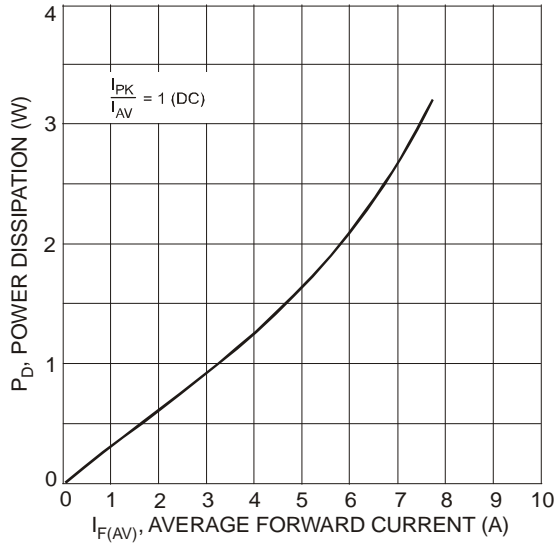


Fig. 1 Forward Power Dissipation

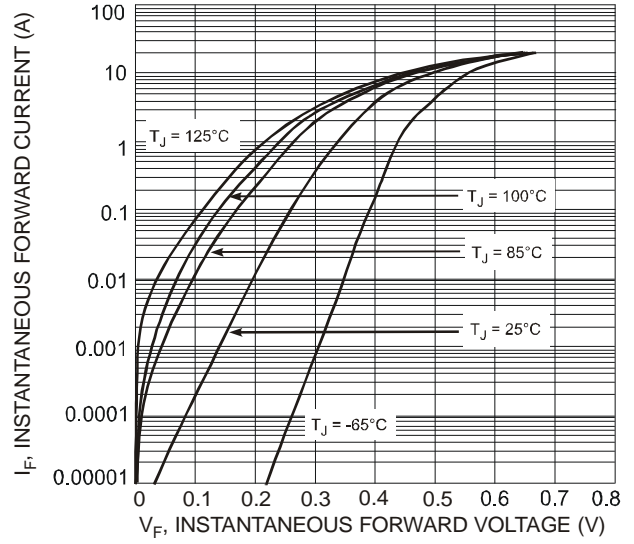


Fig. 2 Typical Forward Characteristics

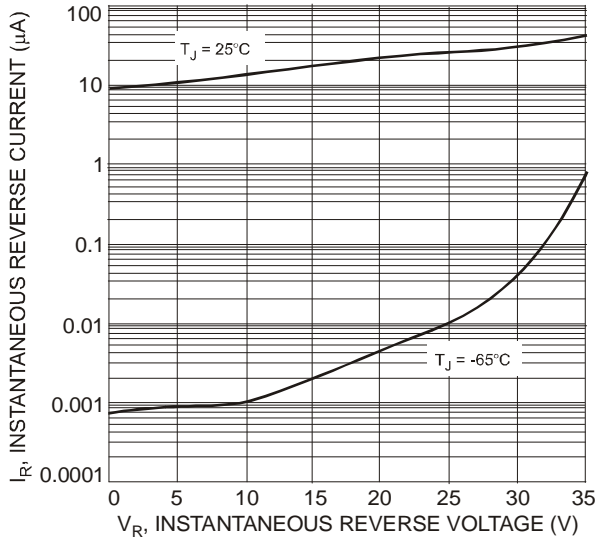


Fig. 3 Typical Reverse Characteristics

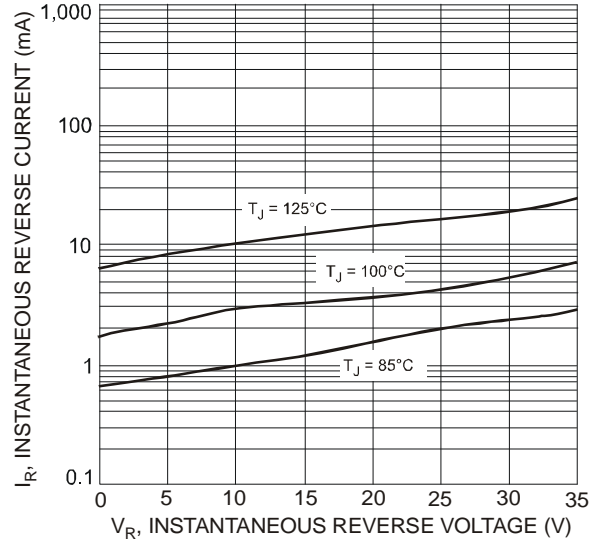


Fig. 4 Typical Reverse Characteristics

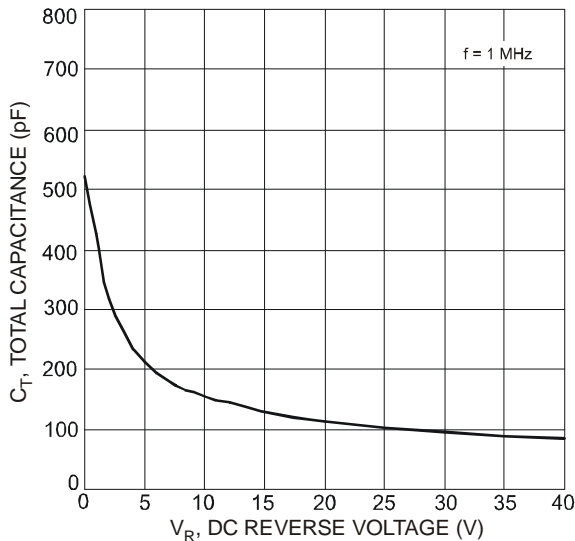


Fig. 5 Total Capacitance vs. Reverse Voltage

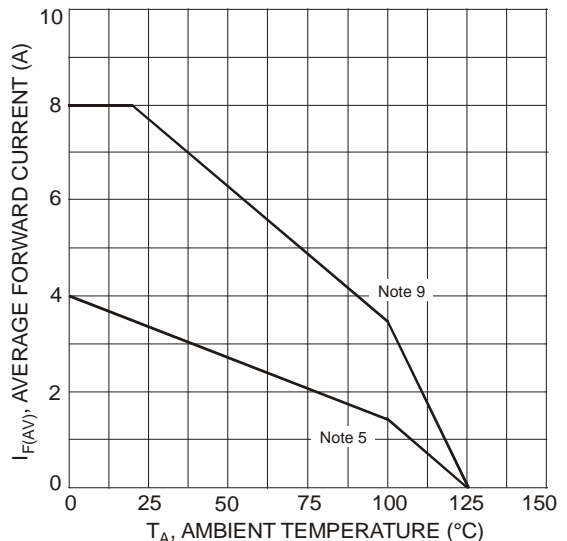


Fig. 6 Forward Current Derating Curve

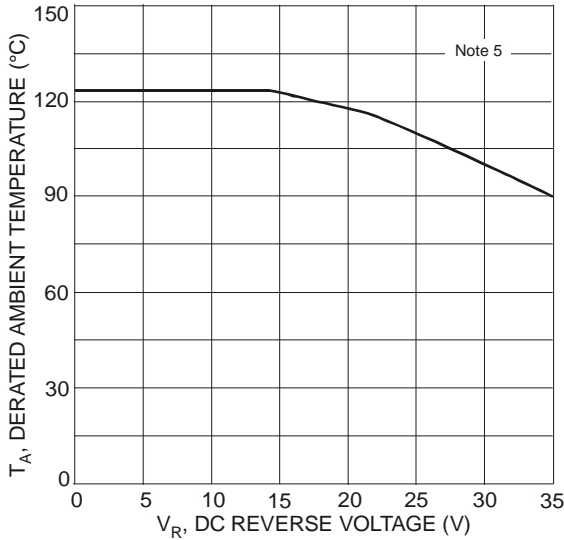
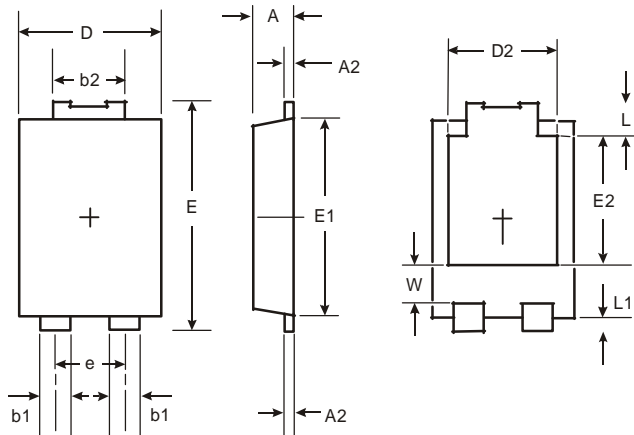


Fig. 7 Operating Temperature Derating

Notes: 9. Polyimide PCB, 2 oz. Copper. Cathode pad dimensions 18.8mm x 14.4mm. Anode pad dimensions 5.6mm x 3.0mm.

Package Outline Dimensions

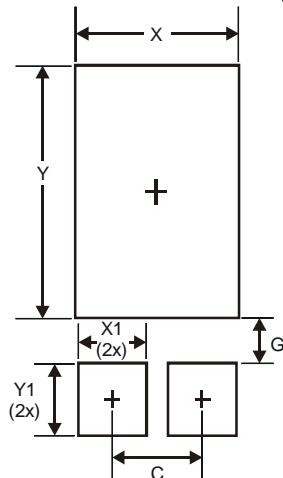
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



POWERDI5		
Dim	Min	Max
A	1.05	1.15
A2	0.33	0.43
b1	0.80	0.99
b2	1.70	1.88
D	3.90	4.05
D2	3.054 Typ	
E	6.40	6.60
e	1.84 Typ	
E1	5.30	5.45
E2	3.549 Typ	
L	0.75	0.95
L1	0.50	0.65
W	1.10	1.41
All Dimensions in mm		

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	1.840
G	0.852
X	3.360
X1	1.390
Y	4.860
Y1	1.400

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